

isc N-Channel MOSFET Transistor

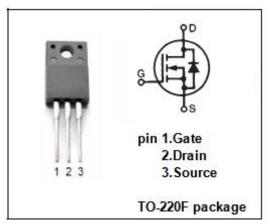
AOTF260L

• FEATURES

- Drain Current –I_D= 92A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 2.6m \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

 Be suitable for synchronous rectification for server and general purpose applications

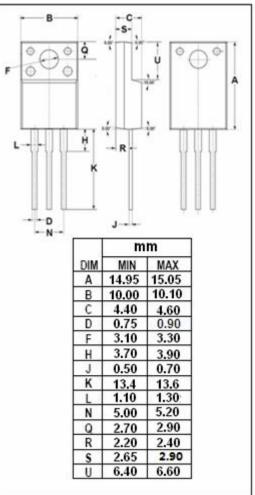


• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	60	V
V _G s	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	92	Α
I _{DM}	Drain Current-Single Pulsed	368	Α
P _D	Total Dissipation @Tc=25℃	46.5	W
Tj	Max. Operating Junction Temperature	-55~175	$^{\circ}$
T _{stg}	Storage Temperature	-55~175	℃

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.2	°C/W



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 250 μ A	60		V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = V _{GS} ; ID = 250 μ A	2.2	3.2	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 20A V _{GS} = 10V; I _D = 20A;T _J =125°C		2.6 4.3	m Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V		±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 60V; V _{GS} = 0V V _{DS} = 60V; V _{GS} = 0V; T _J = 55°C		1 5	μА
V_{SD}	Diode forward voltage	Is= 1A; V _{GS} = 0V		1	V

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